

update 10/820,841

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	94	(negative adj voltage) and (finite near state near machine)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/26 10:37
L2	3	(negative adj voltage) same (finite near state near machine)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/26 10:34
L3	11	1 and (standby or (stand near by))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/26 10:35
L4	1	(back near gate near voltage) and (finite near state near machine)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/26 10:38
S1	72	back-gate adj voltage	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/26 10:32
S34	16	S32 or S33	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/19 07:45
S36	17	double-gate adj (thin adj film adj transistor)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/19 07:45
S37	3	double-gate adj (thin-film adj transistor)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/19 07:45
S38	17	S36 or S37	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/19 08:04
S39	1	(standby or (stand near by)) and operating and (back near gate near voltage) and (finite near state near machine)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/19 08:07

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S40	1	(back near gate near voltage) and (finite near state near machine)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/19 08:07
S41	100	(negative near voltage) and (finite near state near machine)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/19 08:07
S42	11	(standby or (stand near by)) and operating and (negative near voltage) and (finite near state near machine)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/19 08:09
S43	8	((("6107830") or ("5450025") or ("6268748") or ("6240019")).PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/01/19 08:09

Interference Search 10/820,841

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L5	1	((back near gate near voltage) and (finite near state near machine)).dm.	US-PGPUB	OR	ON	2006/01/26 11:09
L6	0	((back near gate near voltage) and (communicating near sequential near processes)).dm.	US-PGPUB	OR	ON	2006/01/26 11:10
L7	1	((back near gate near voltage) and csp).dm.	US-PGPUB	OR	ON	2006/01/26 11:10